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# CD4007C Dual Complementary Pair Plus Inverter

#### **General Description**

The CD4007C consists of three complementary pairs of Nand P-channel enhancement mode MOS transistors suitable for series/shunt applications. All inputs are protected from static discharge by diode clamps to V<sub>DD</sub> and V<sub>SS</sub>. For proper operation the voltages at all pins must be constrained to be between  $V_{SS}$  – 0.3V and  $V_{DD}$  + 0.3V at all times.

October 1987

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#### Features

- Wide supply voltage range: 3.0V to 15V
- High noise immunity: 0.45 V<sub>CC</sub> (typ.)

## **Ordering Code:**

Order Number	Package Number	Package Description				
CD4007CM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow				
CD4007CN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide				
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.						

### **Connection Diagram**



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## Absolute Maximum Ratings(Note 1)

Voltage at Any Pin Operating Temperature Range	$V_{SS}$ –0.3V to $V_{DD}$ +0.3V –40°C to +85°C	Operating V <sub>DD</sub> Range	$\rm V_{SS}$ +3.0V to $\rm V_{SS}$ +15V $\rm 260^{\circ}C$		
Storage Temperature Range Power Dissipation (P <sub>D</sub> )	-65°C to +150°C	Lead Temperature (Soldering, 10 seconds)			
Dual-In-Line Small Outline	700 mW 500 mW	Note 1: This device should not be connected to circuits with the power on because high transient voltages may cause permanent damage.			

## **DC Electrical Characteristics**

		Conditions	Limits									
Symbol	Parameter		<b>−40°C</b>		+25°C			+85°C			Units	
			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
IL.	Quiescent Device	$V_{DD} = 5.0V$			0.5		0.005	0.05			15	μΑ
	Current	$V_{DD} = 10V$			1.0		0.005	1.0			30	μΑ
PD	Quiescent Device	$V_{DD} = 5.0V$			2.5		0.025	2.5			75	μW
	Dissipation Package	$V_{DD} = 10V$			10		0.05	10			300	μW
V <sub>OL</sub>	Output Voltage	$V_{DD} = 5.0V$			0.05		0	0.01			0.05	V
	LOW Level	$V_{DD} = 10V$			0.05		0	0.01			0.05	V
V <sub>OH</sub>	Output Voltage	$V_{DD} = 5.0V$	4.95			4.95	5.0		4.95			V
	HIGH Level	$V_{DD} = 10V$	9.95			9.95	10		9.95			V
V <sub>NL</sub>	Noise Immunity	$V_{DD} = 5.0V, V_{O} = 3.6V$			1.5		2.25	1.5			1.4	V
	(All inputs)	$V_{DD} = 10V, V_{O} = 7.2V$			3.0		4.5	3.0			2.9	V
V <sub>NH</sub>	Noise Immunity	$V_{DD} = 5.0V, V_{O} = 0.95V$	3.6			3.5	2.25		3.5			V
	(All Inputs)	$V_{DD} = 10V, V_{O} = 2.9V$	7.1			7.0	4.5		7.0			V
I <sub>D</sub> N	Output Drive Current	$V_{DD} = 5.0V, V_{O} = 0.4V, V_{I} = V_{DD}$	0.35			0.3	1.0		0.24			mA
	N-Channel	$V_{DD}=10V,V_O=0.5V,V_I=V_{DD}$	1.2			1.0	2.5		0.8			mA
I <sub>D</sub> P	Output Drive Current	$V_{DD} = 5.0V, V_{O} = 2.5V, V_{I} = V_{SS}$	-1.3			-1.1	-4.0		-0.9			mA
	P-Channel	$V_{DD}$ = 10V, $V_{O}$ = 9.5V, $V_{I}$ = $V_{SS}$	-0.65			-0.55	-2.5		-0.45			mA
l <sub>l</sub>	Input Current						10					pА

## AC Electrical Characteristics (Note 2)

$T_A = 25^{\circ}C$ and $C_L = 15 \text{ pF}$ and rise and fall times = 20 ns. Typical temperature coefficient for all values of $V_{DD} = 0.3\%$ /°C							
Symbol	Parameter	Conditions	Min	Тур	Max	Units	
$t_{PLH} = t_{PHL}$	Propagation Delay Time	V <sub>DD</sub> = 5.0V		35	75	ns	
		$V_{DD} = 10V$		20	50	ns	
$t_{TLH} = t_{THL}$	Transition Time	V <sub>DD</sub> = 5.0V		50	100	ns	
		$V_{DD} = 10V$		30	50	ns	
CI	Input Capacitance	Any Input		5		pF	

Note 2: AC Parameters are guaranteed by DC correlated testing.







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